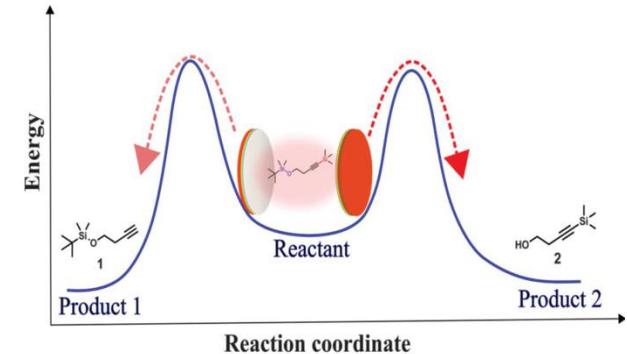
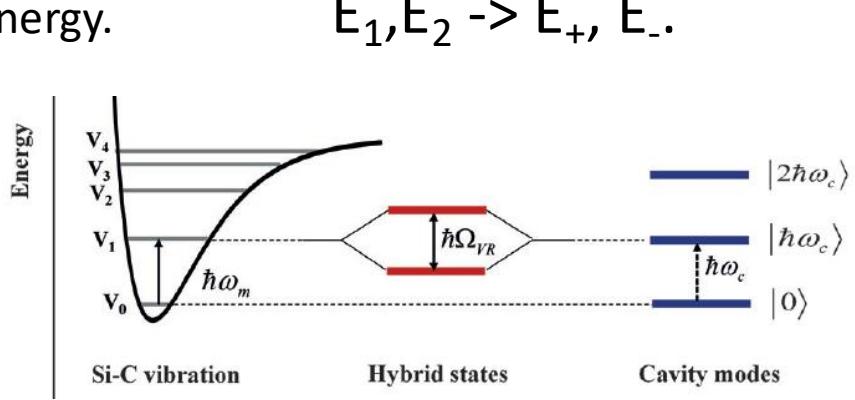
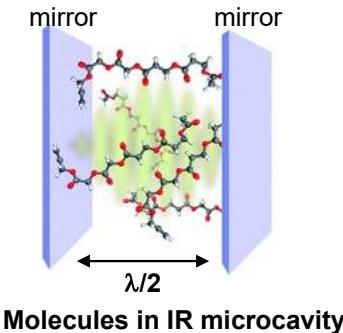


Real-Space Observation of Ultrastrong Coupling Between Optical Phonons and Surface Plasmon Polaritons

Strong coupling

Two systems interact so strongly that they exchange energy faster than they lose it to their environments. $g > \text{losses}$
Change of excitation energy. $E_1, E_2 \rightarrow E_+, E_-$.

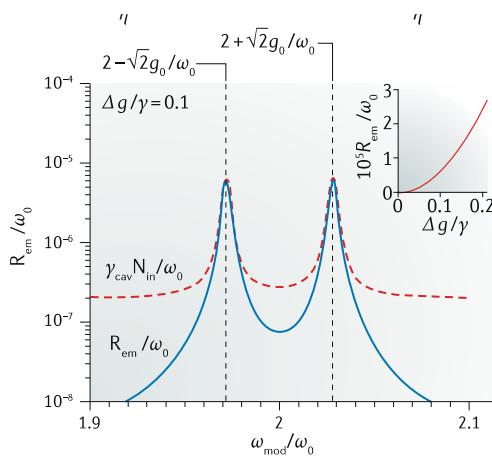
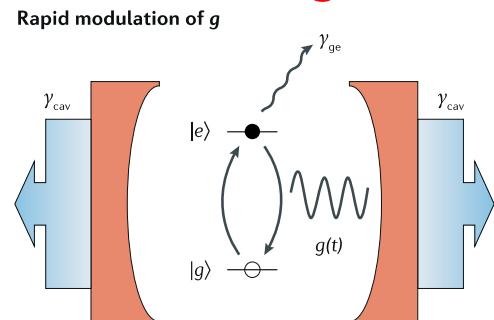
Vibrational
strong
coupling



Ultra-strong coupling

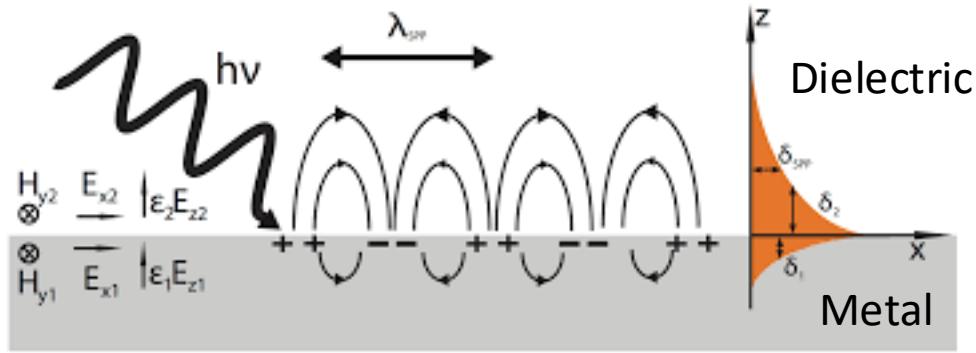
Energy exchange faster than oscillator dynamics . $g > 0.1\omega$

Ground state modification.

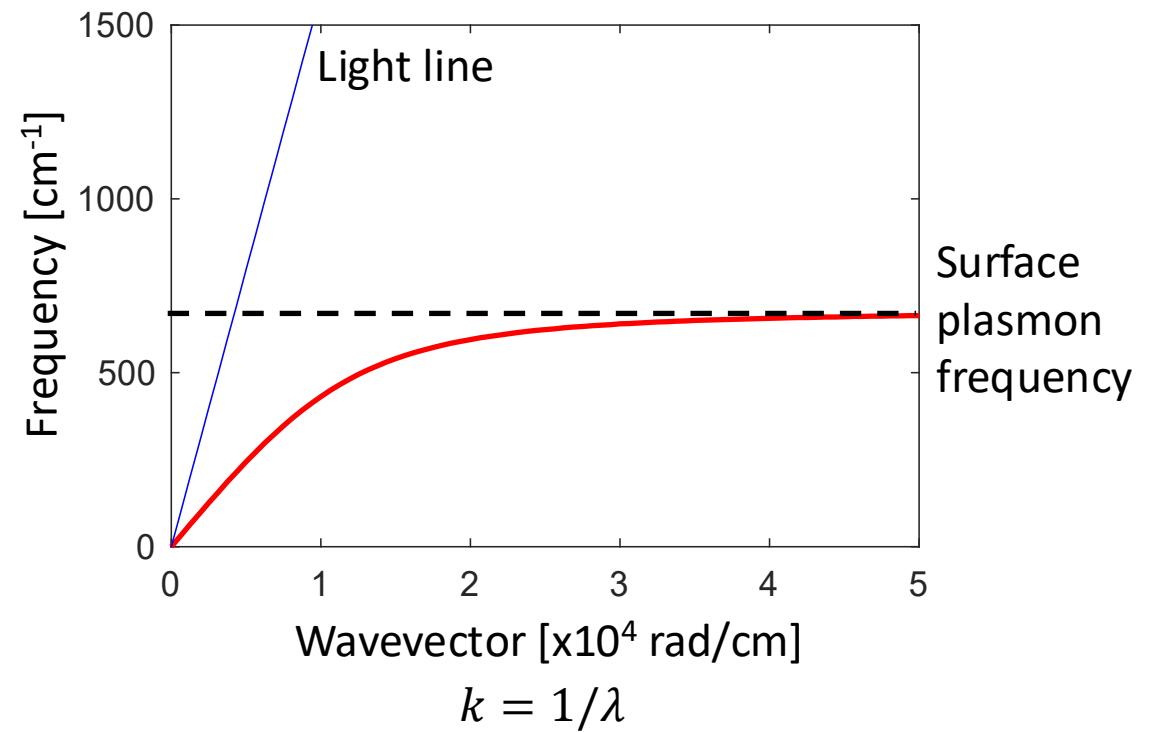


- T. Ebbesen, *Acc. Chem. Res.* **49**, 2403 (2016)
A. Thomas et al., *Angew. Chem. Int.* **55**, 11462 (2016)
A. Thomas et al., *Science* **363**, 615 (2019)
F. Kockum. *Nat Rev Phys* **1**, 19 (2019)

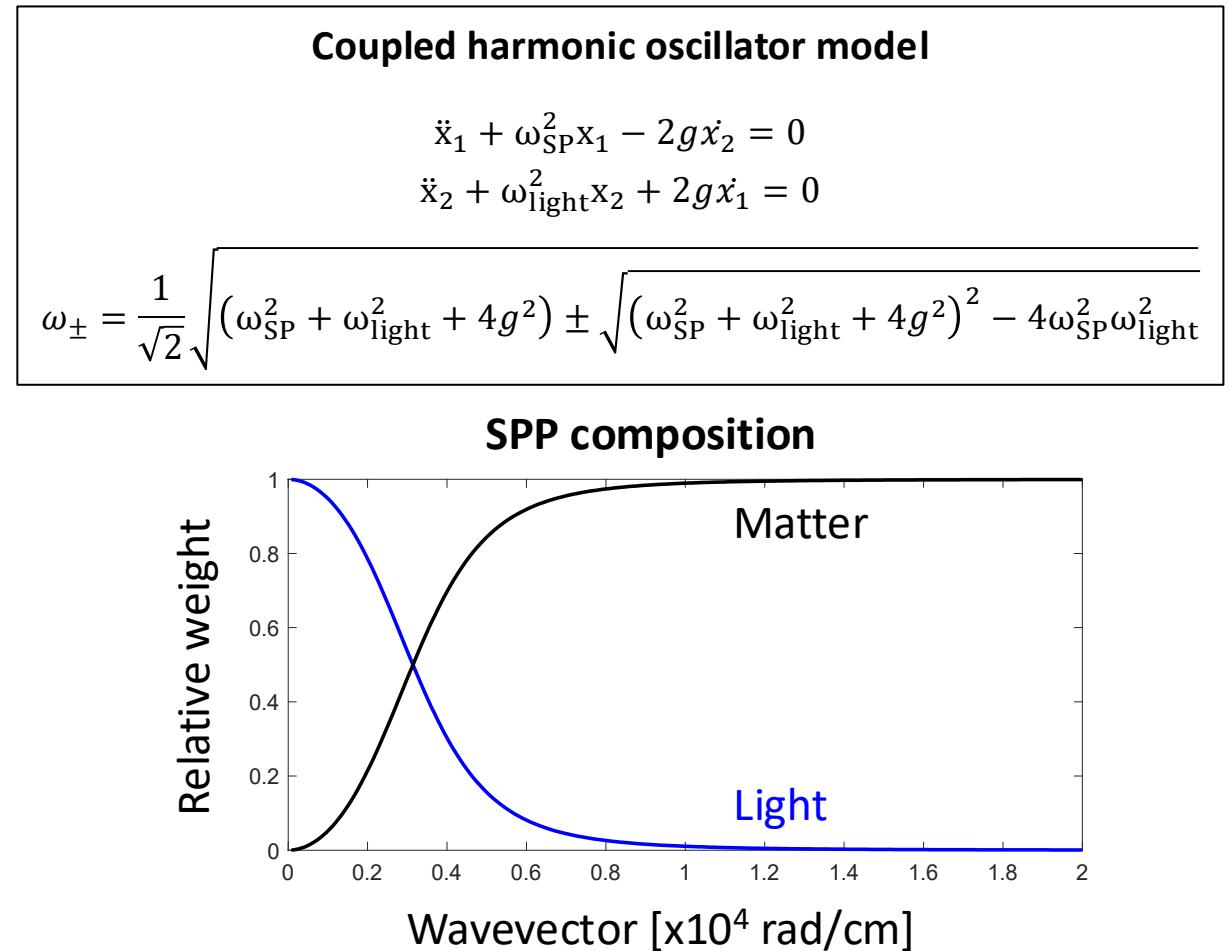
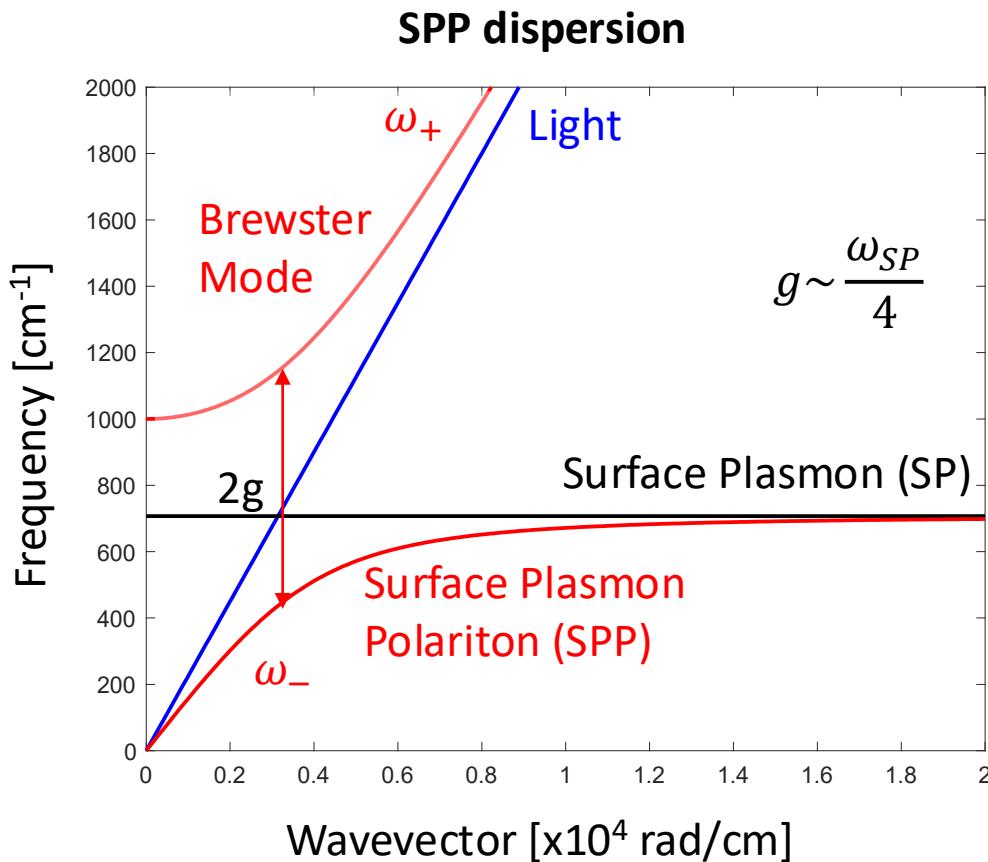
Surface plasmon polariton is the consequence of light-matter coupling



Surface Plasmon polariton is coupling between light and matter.



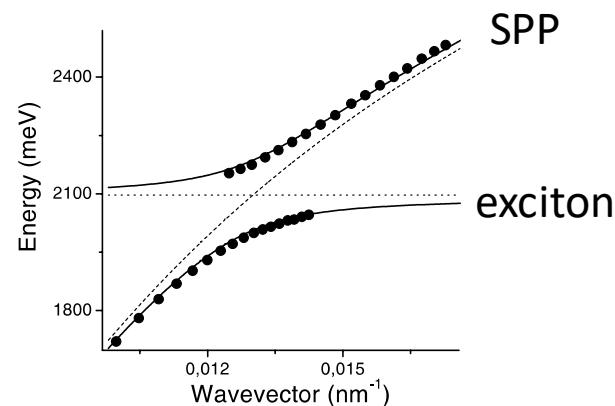
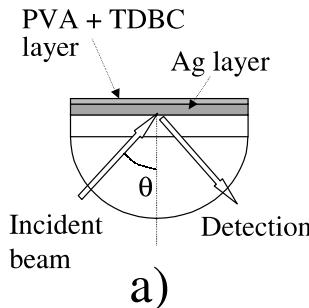
Surface plasmon polariton is the consequence of ultra-strong light-matter coupling



Strong Coupling of surface plasmon polariton with ...

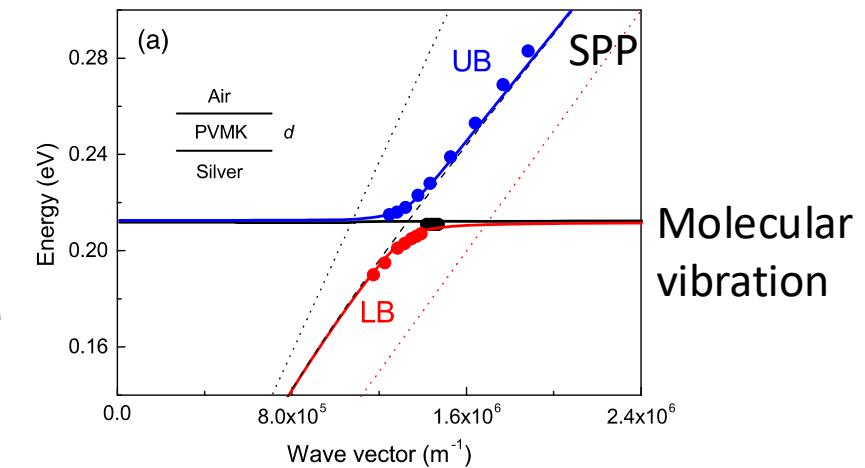
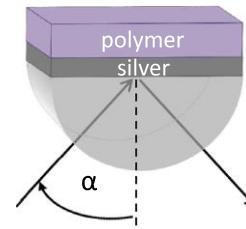
Surface plasmon polaritons have been used to achieve strong coupling with excitons or molecular vibrations thanks to its high confinement ($g \propto \sqrt{V_{overlap}}$).

Excitons



J. Bellessa Phys. Rev. Lett. 93, 03640 2004

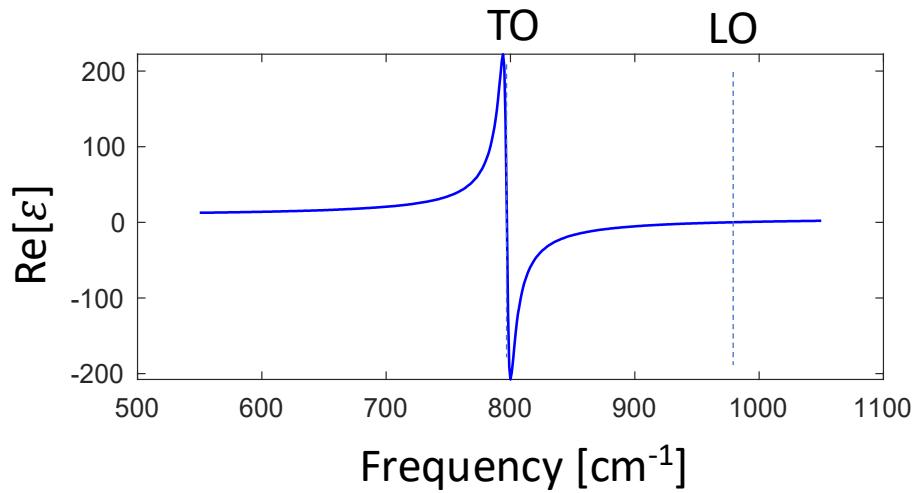
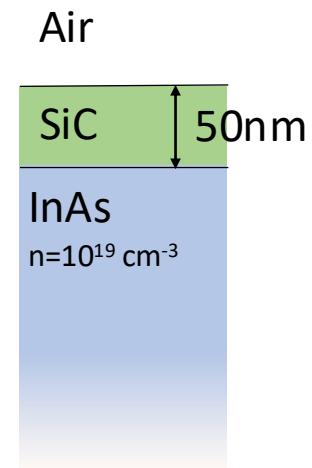
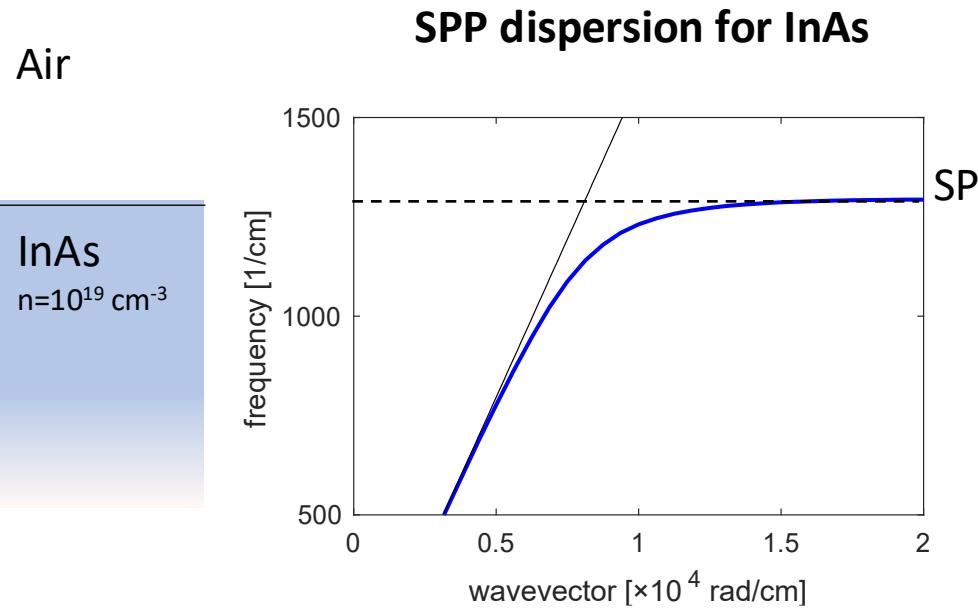
Molecules



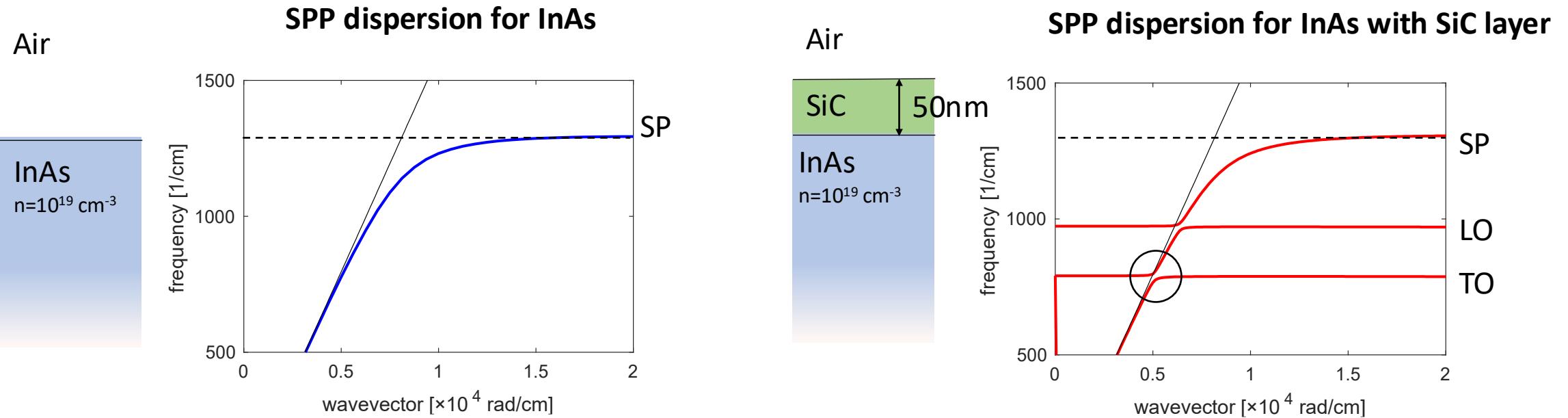
H. Memmi, Phys. Rev. Lett. 118, 126802
2017

But few study of strong coupling with phonons...

Coupling InAs's SPP with SiC phonons

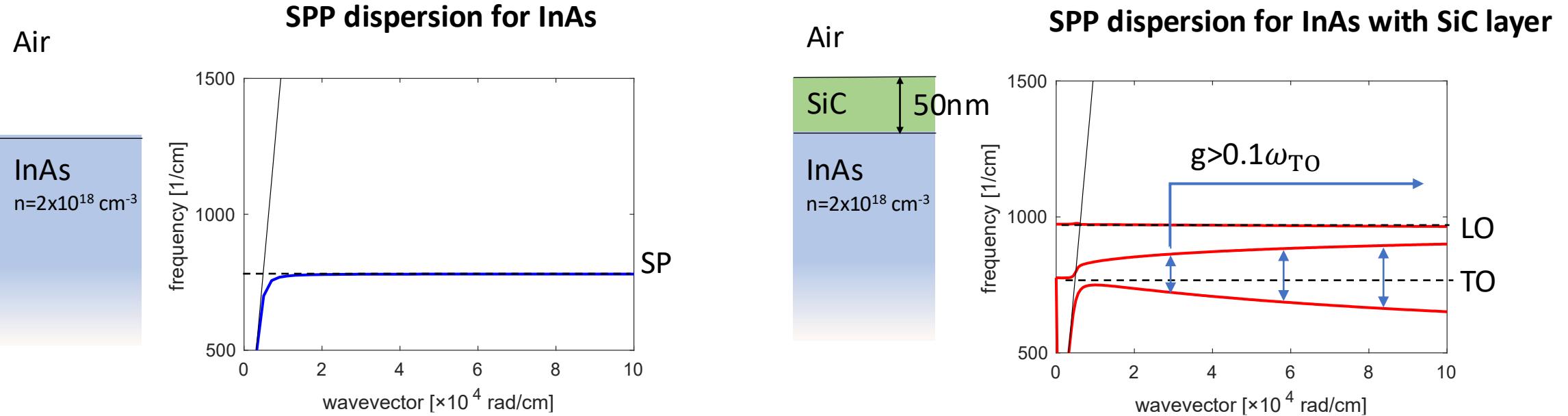


Coupling InAs's SPP with SiC transverse optical phonons



- Anti-crossing at SiC TO phonons frequency.
- Weak coupling due to low confinement of SPP.
$$g \propto \sqrt{V_{overlap}}$$

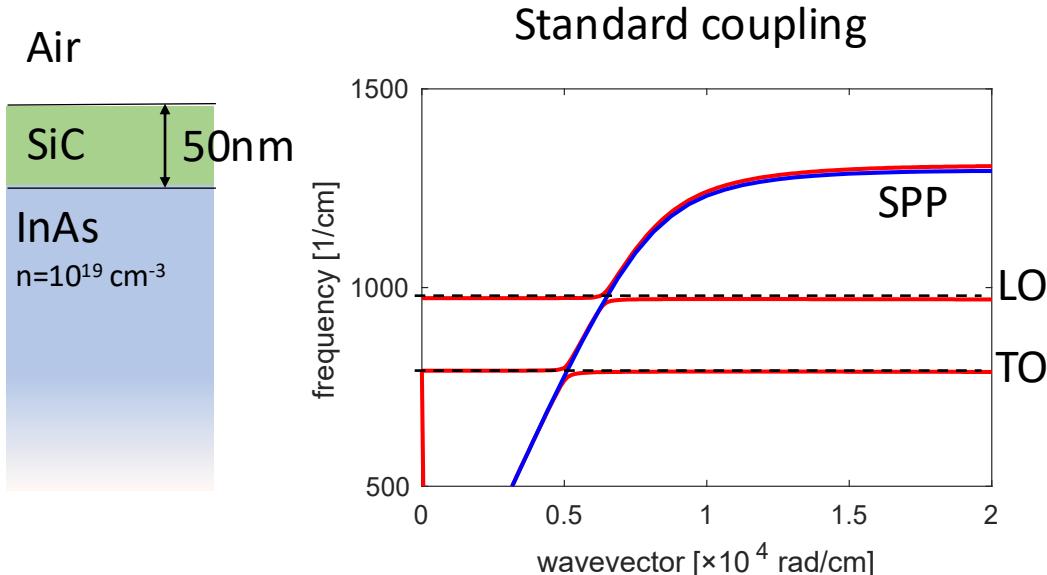
Coupling SPP dispersion limit with SiC TO phonon



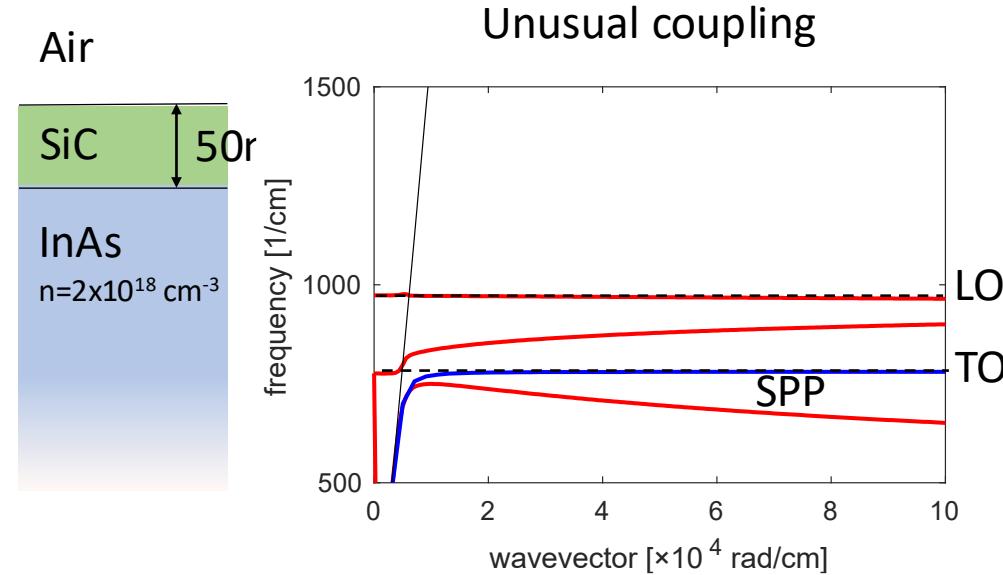
Moving SP to match TO, we identify an unusual coupling.
Ultrastrong coupling between SPP and TO phonon.

Coupling SPP dispersion limit with SiC TO phonon

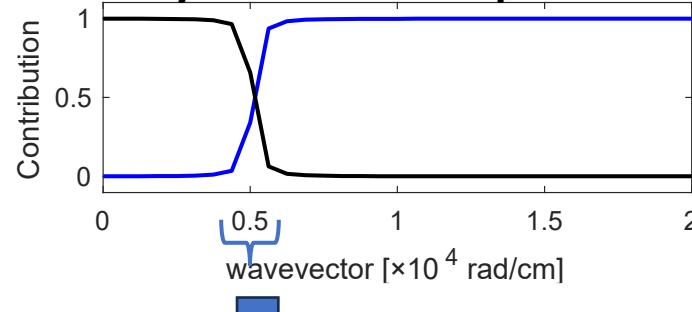
Air



Air

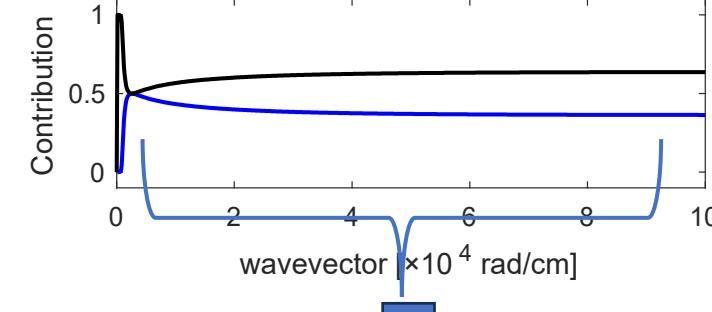


Hybrid mode composition



mixed polariton–phonon state
in a narrow wavevector range

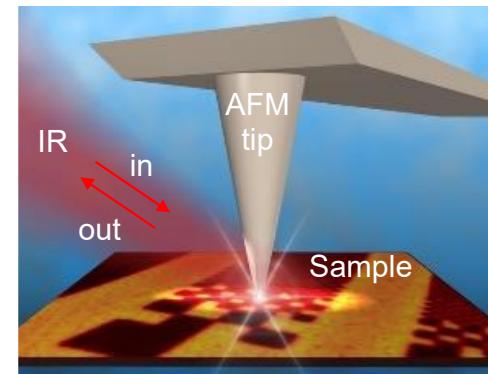
Hybrid mode composition



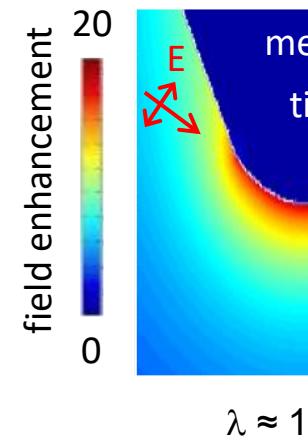
mixed polariton–phonon state
in a wide wavevector range

Detecting polariton with scattering scanning near-field optical microscopy (s-SNOM)

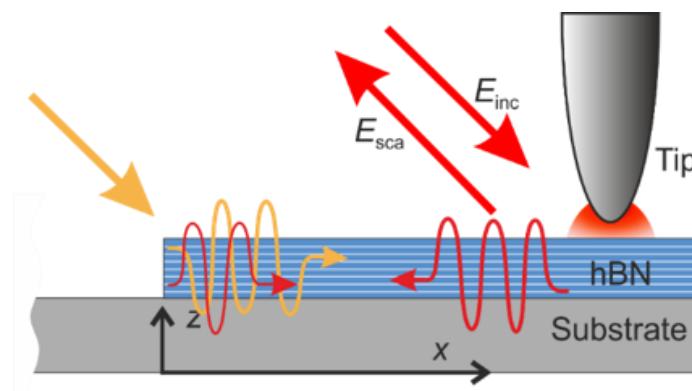
Focused
laser beam
illuminates
AFM tip



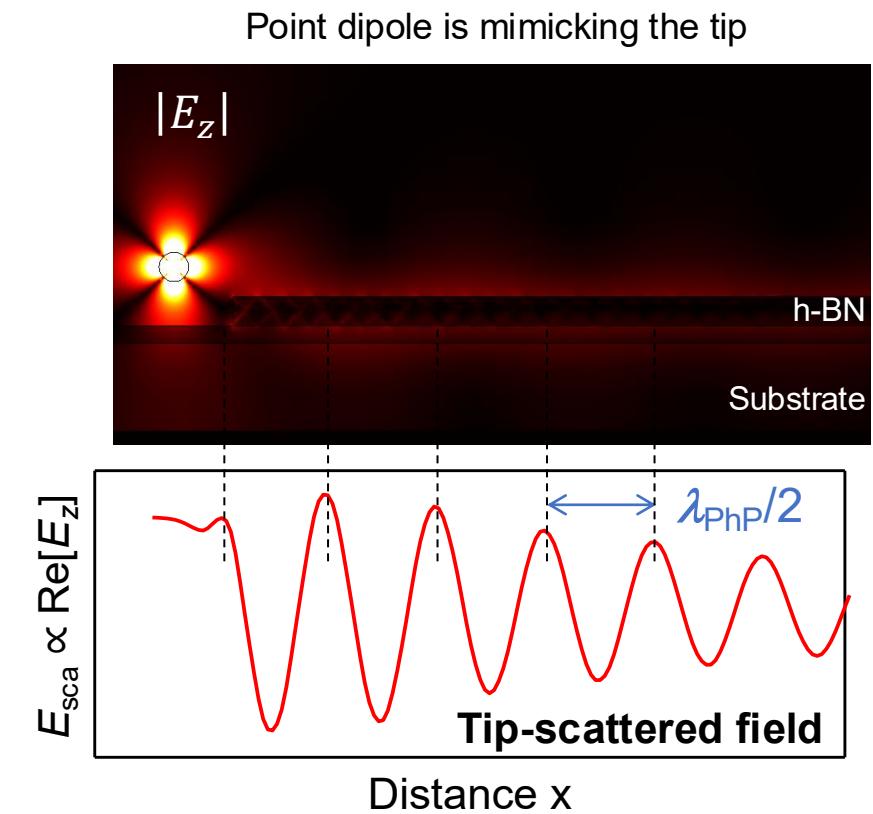
Detection of
back scattered
light



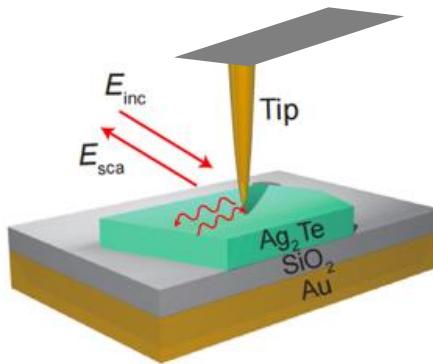
Tip creates
nano-focus



Polariton interferometry for
imaging polaritons

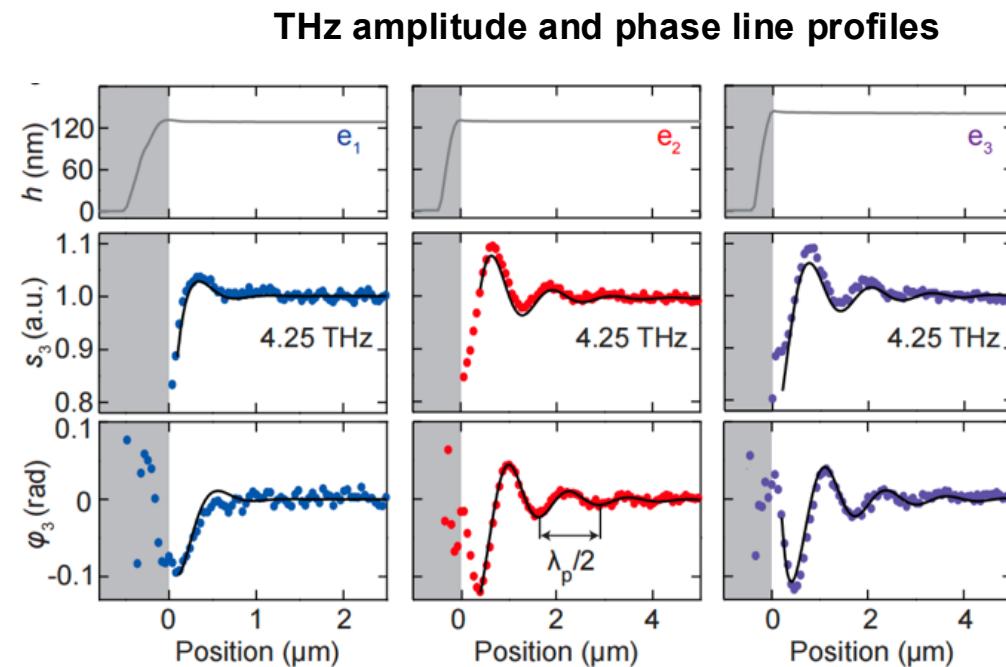
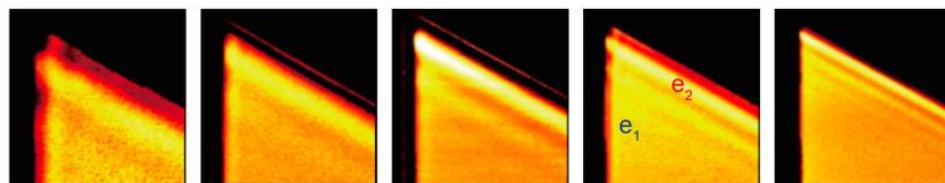
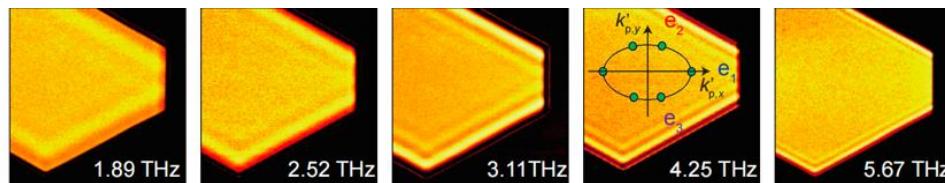


Example of polariton interferometry in anisotropic material



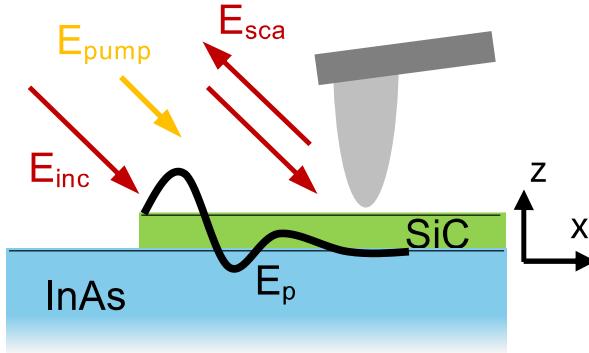
Surface plasmon
polaritons in Ag_2Te

THz near-field amplitude



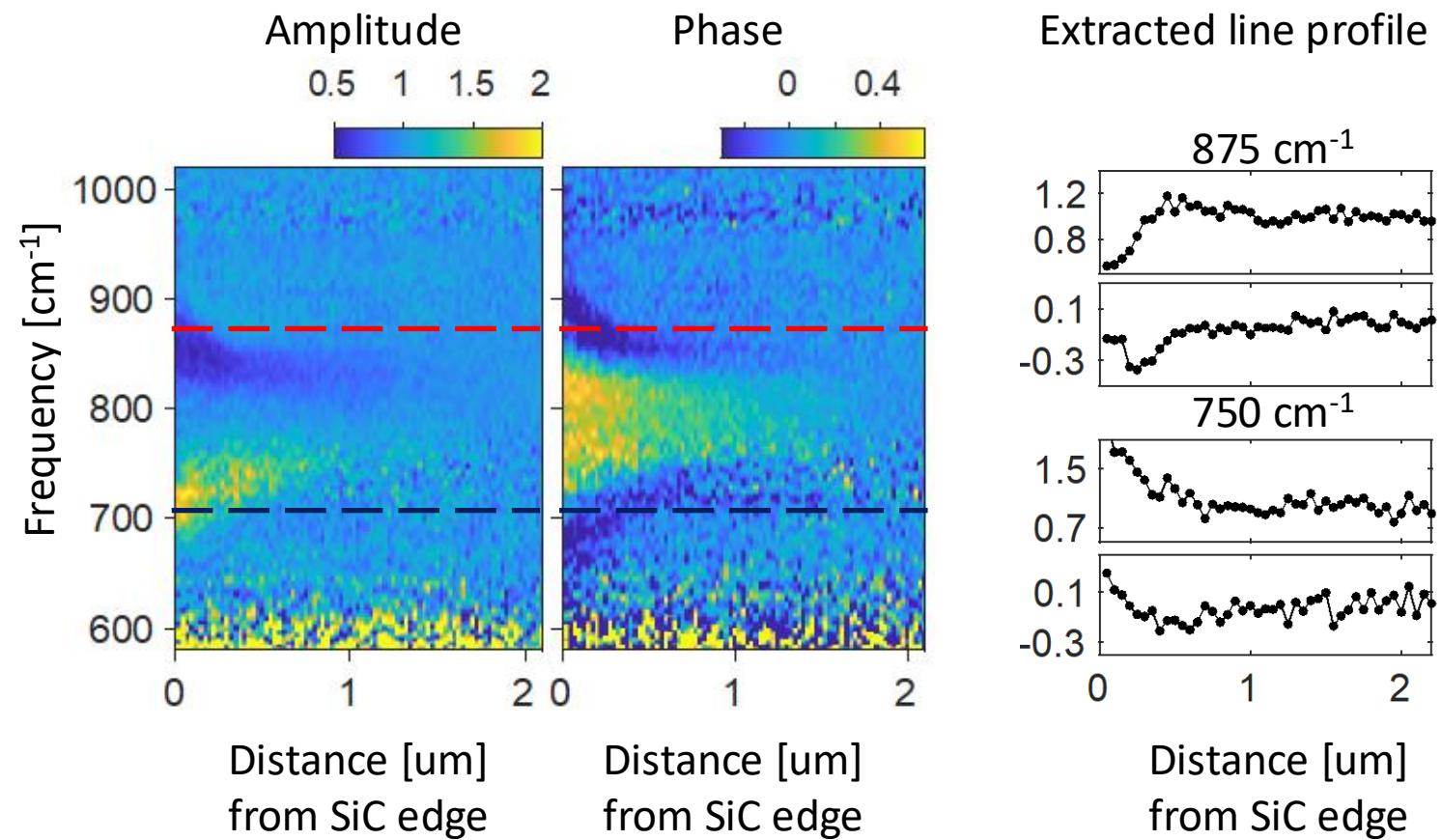
Few oscillation due to small group velocity and high damping

Polariton interferometry of InAs/SiC sample under photodoping

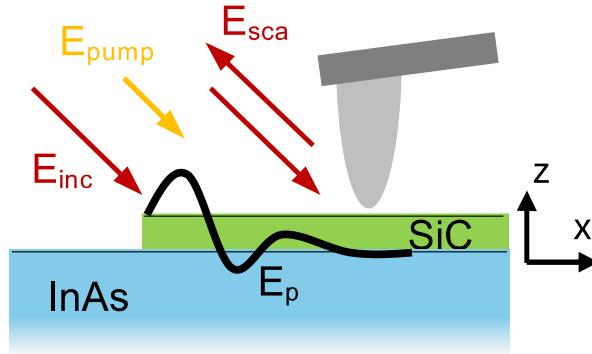


SiC edge launch polariton which is scattered by the AFM tip

Photoexcited InAs
From $n=10^{17} \text{ cm}^{-3}$
to $n=2 \times 10^{18} \text{ cm}^{-3}$



Line profiles can be fitted by a decaying plane wave, yielding polariton wavevector



SiC edge launch polariton which
is scattered by the AFM tip

Photoexcited InAs
From $n=10^{17} \text{ cm}^{-3}$
to $n=2 \times 10^{18} \text{ cm}^{-3}$

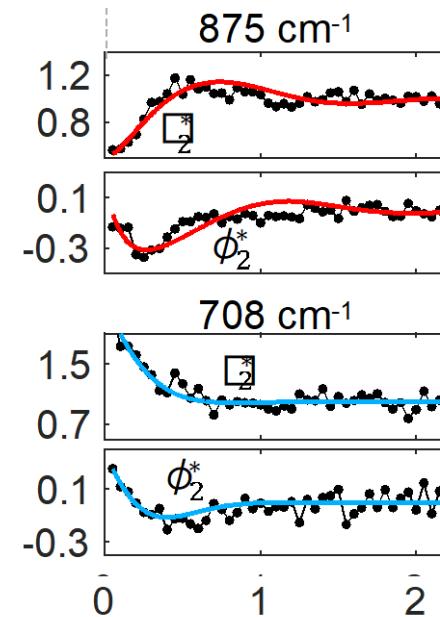
We fit the polariton field with

$$E_p = E_0 e^{ikx} e^{-\gamma x}$$



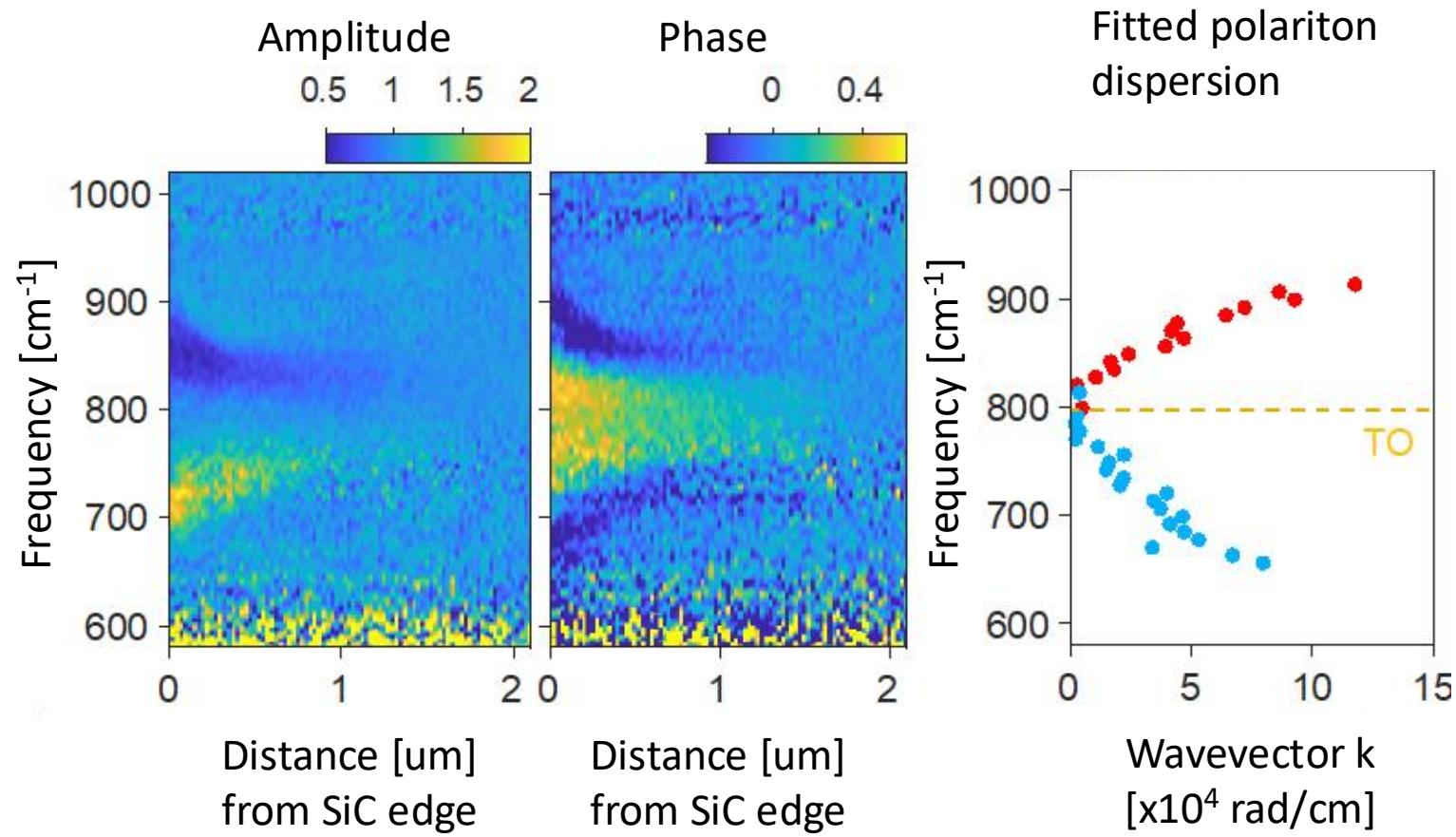
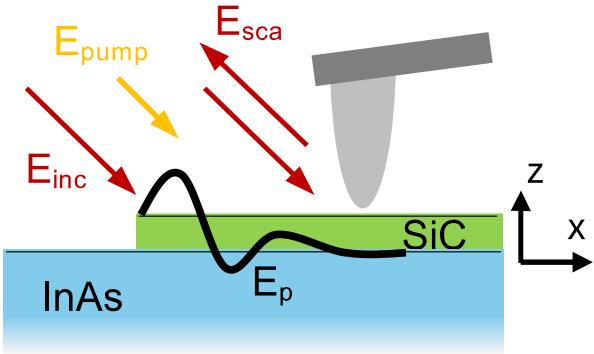
wavevector k

Extracted line profile

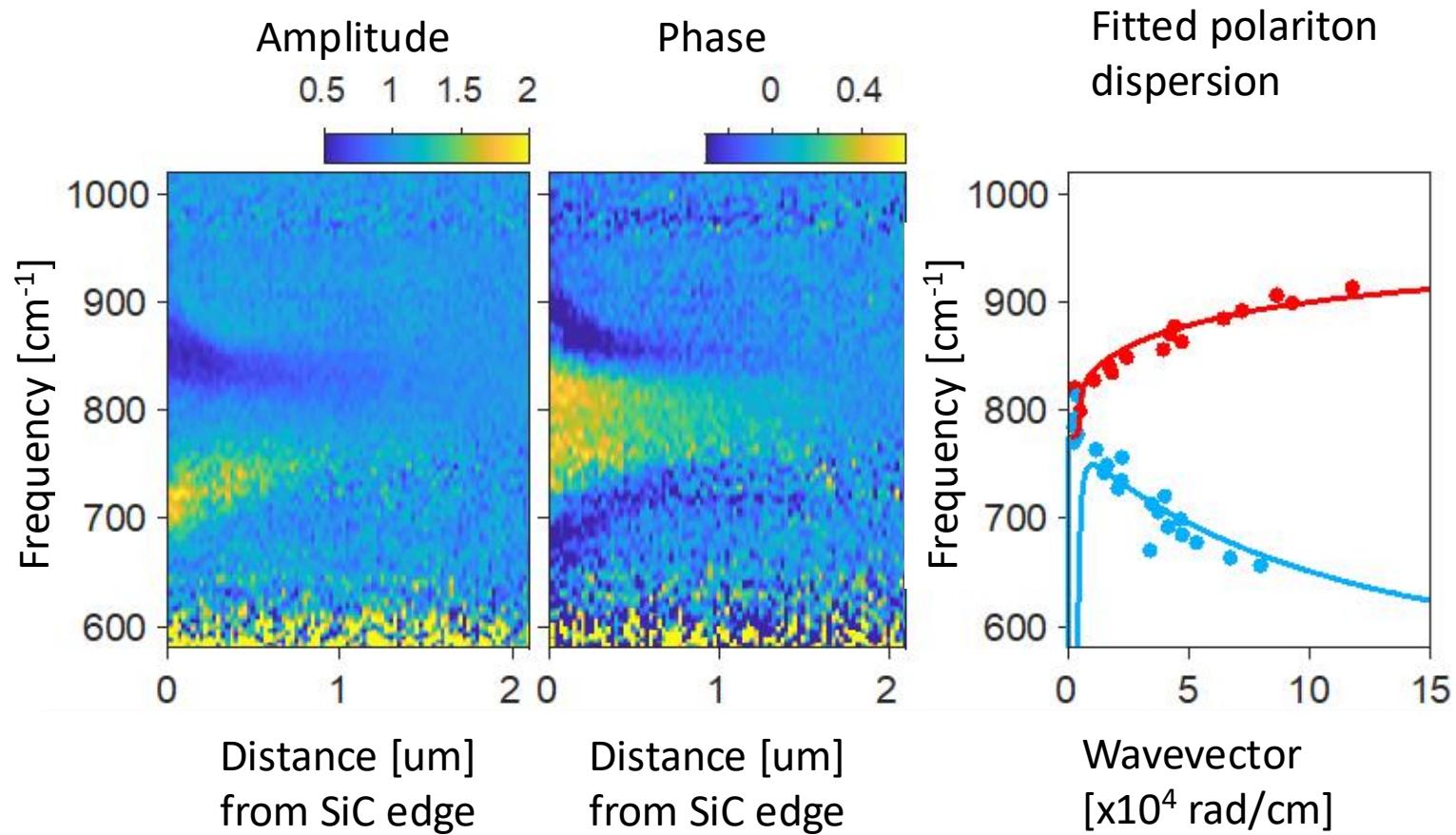
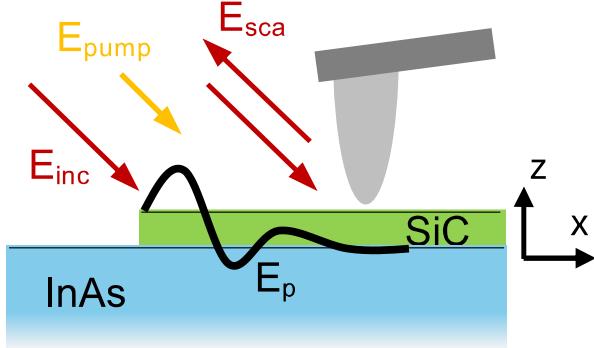


Distance [um]
from SiC edge

Fitting for all frequencies yields dispersion



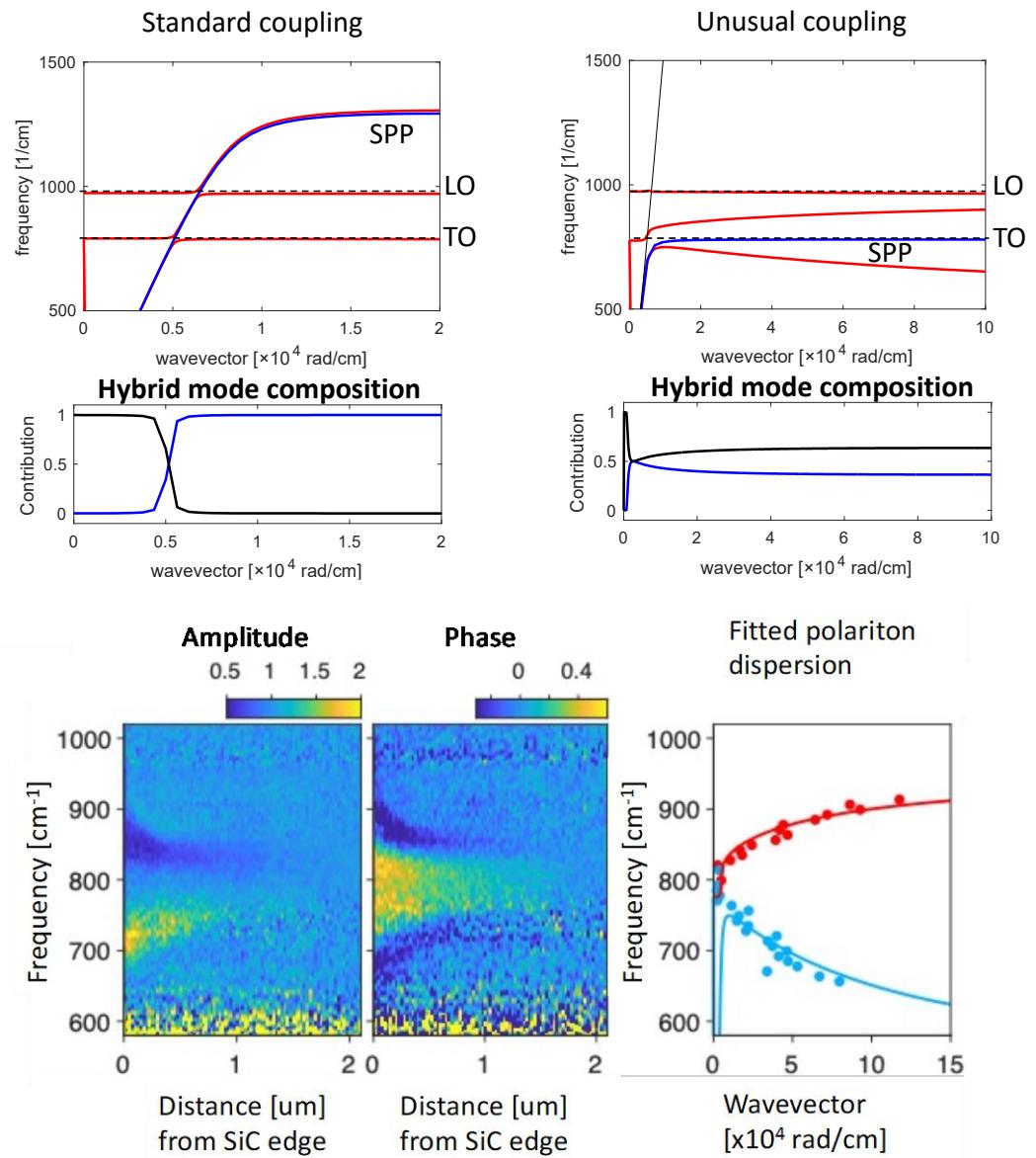
Exp. dispersion matches well the one obtaine from transfer matrix calcs



mixed polariton–phonon state
in a wide wavevector range
experimentally confirmed

Conclusion

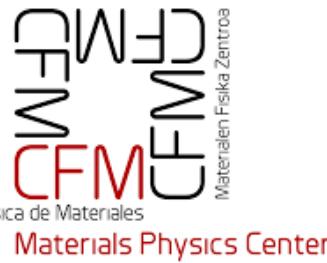
- We studied the coupling between surface plasmon polariton in InAs with TO phonons in SiC.
- We predicted an unusual coupling when we match SPP dispersion with TO.
- We confirmed the predictions by measuring the polariton dispersions by polariton interferometry with s-SNOM.



Acknowledgements



Nanooptics group



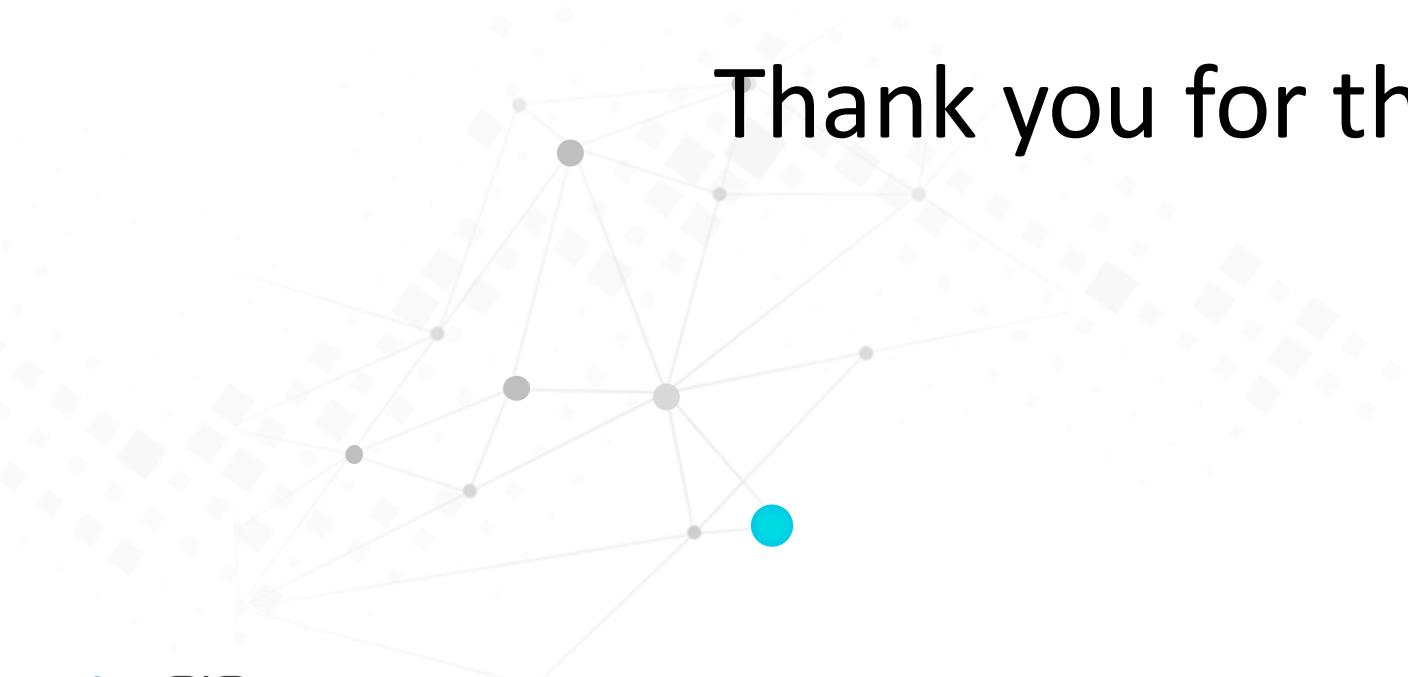
Xabier Arrieta
Ruben Esteban



Javier Aizpurua

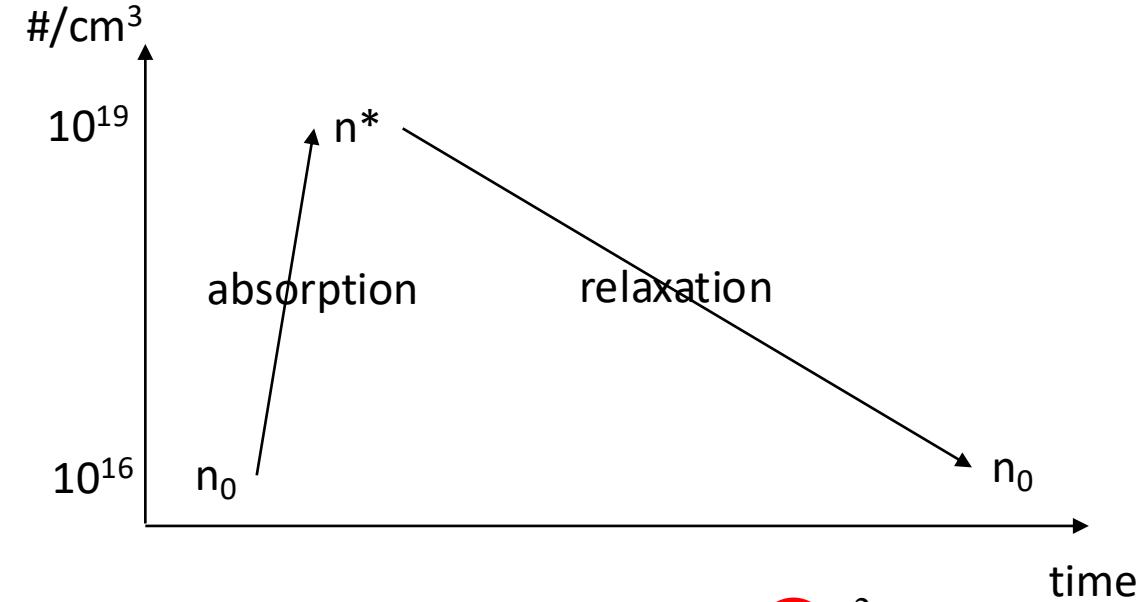
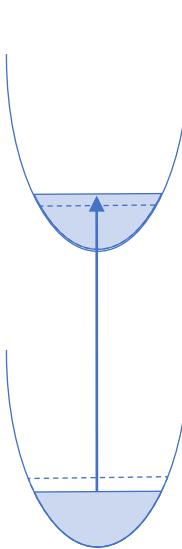
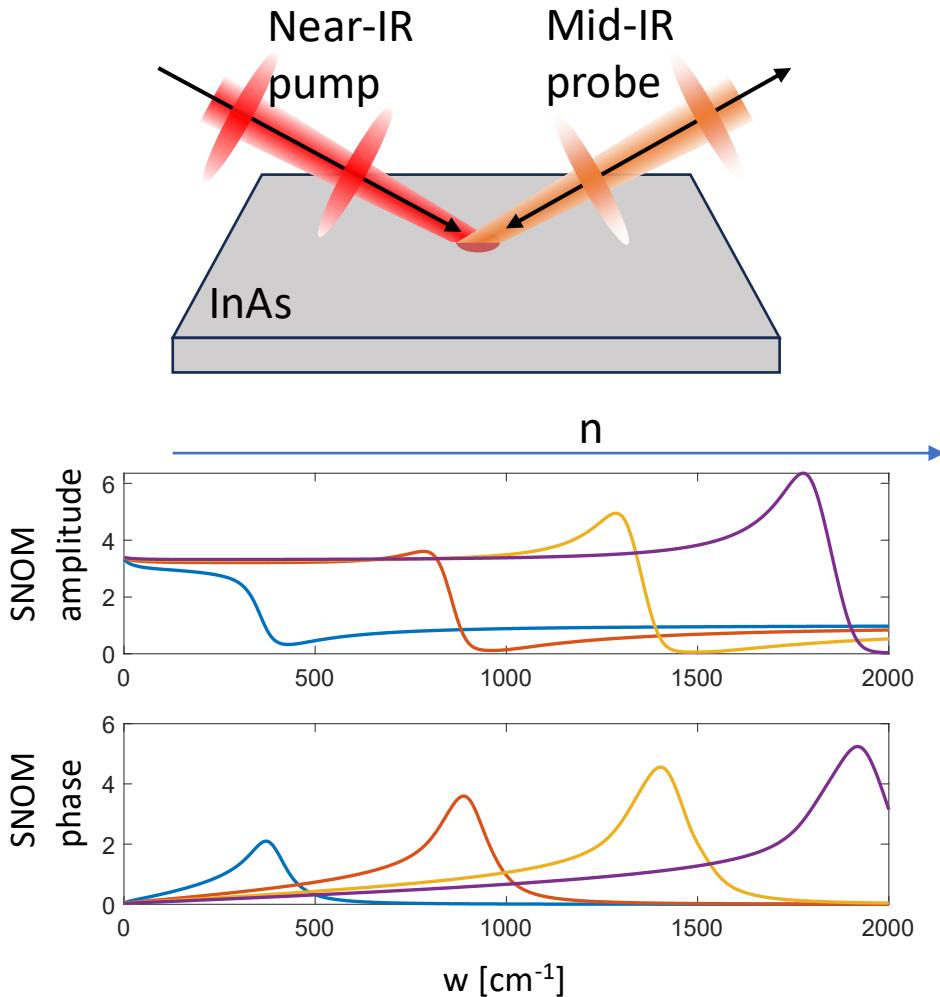
Fundings:





Thank you for the attention

Pump-probe nanospectroscopy



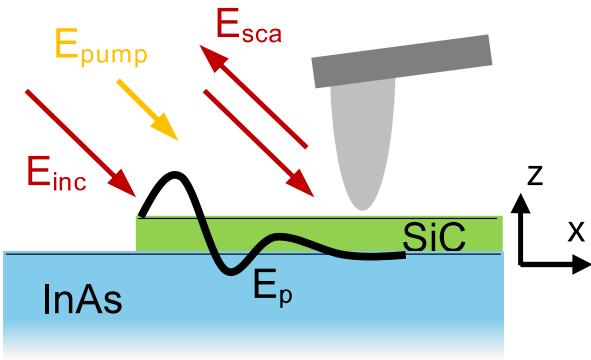
$$\epsilon(\omega) = \epsilon_{\infty} \left[1 - \frac{\omega_p^2}{\omega^2 + i\gamma\omega} \right]$$

$$\omega_p^2 = \frac{n e^2}{\epsilon_0 \epsilon_{\infty} m m_0}$$

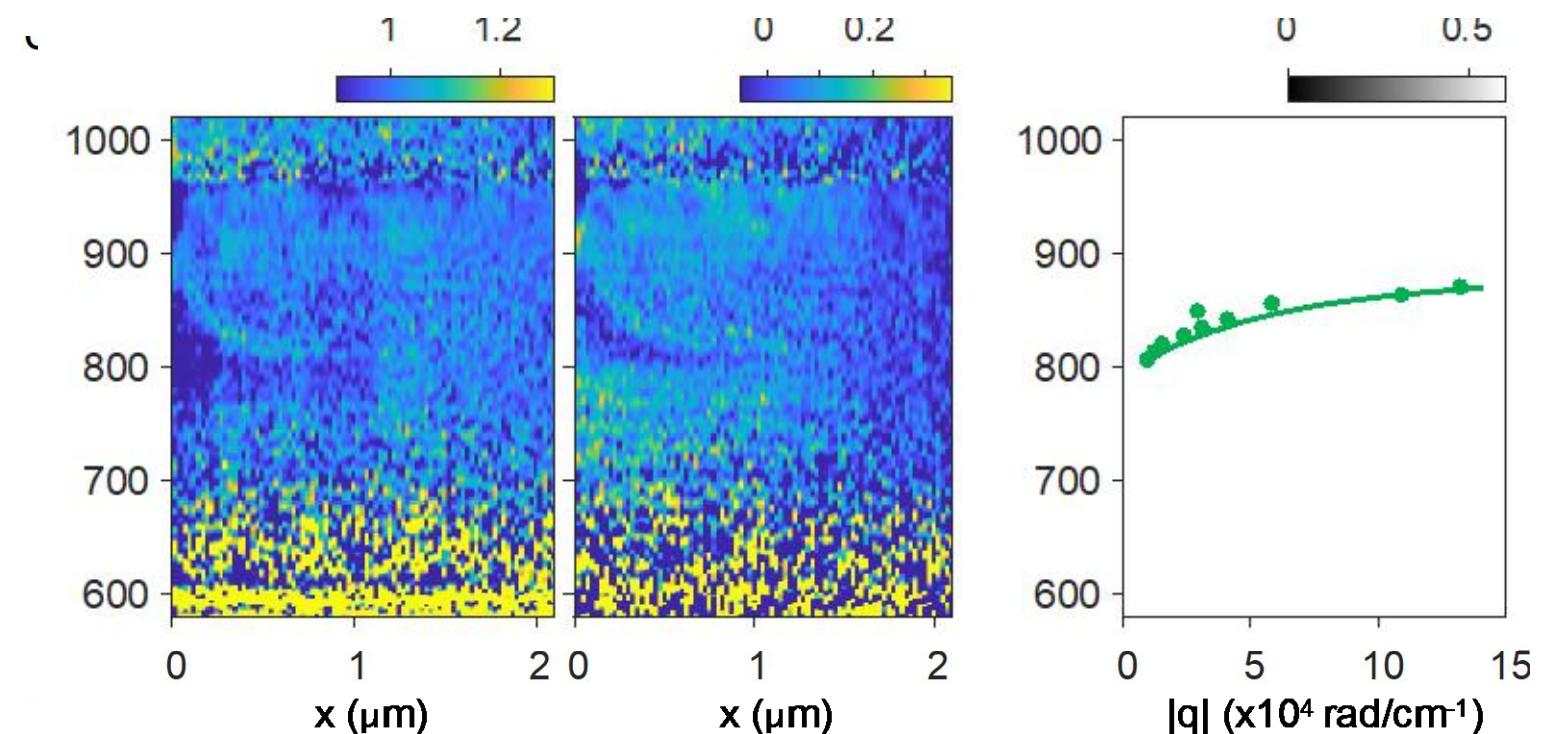
Pump-probe nanospectroscopy to photoexcite carriers in semiconductors and probe plasmon response

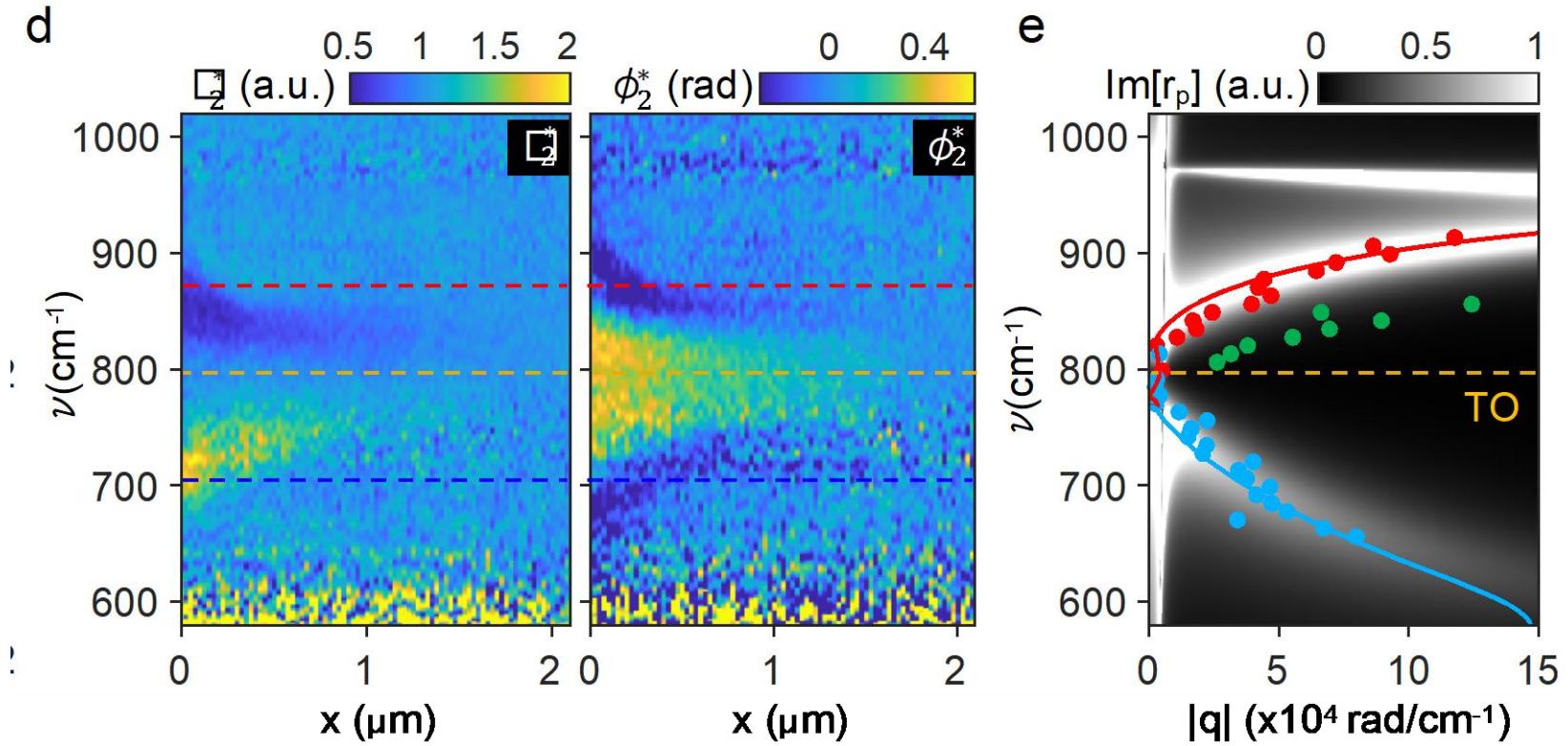
Polariton interferometry InAs/SiC

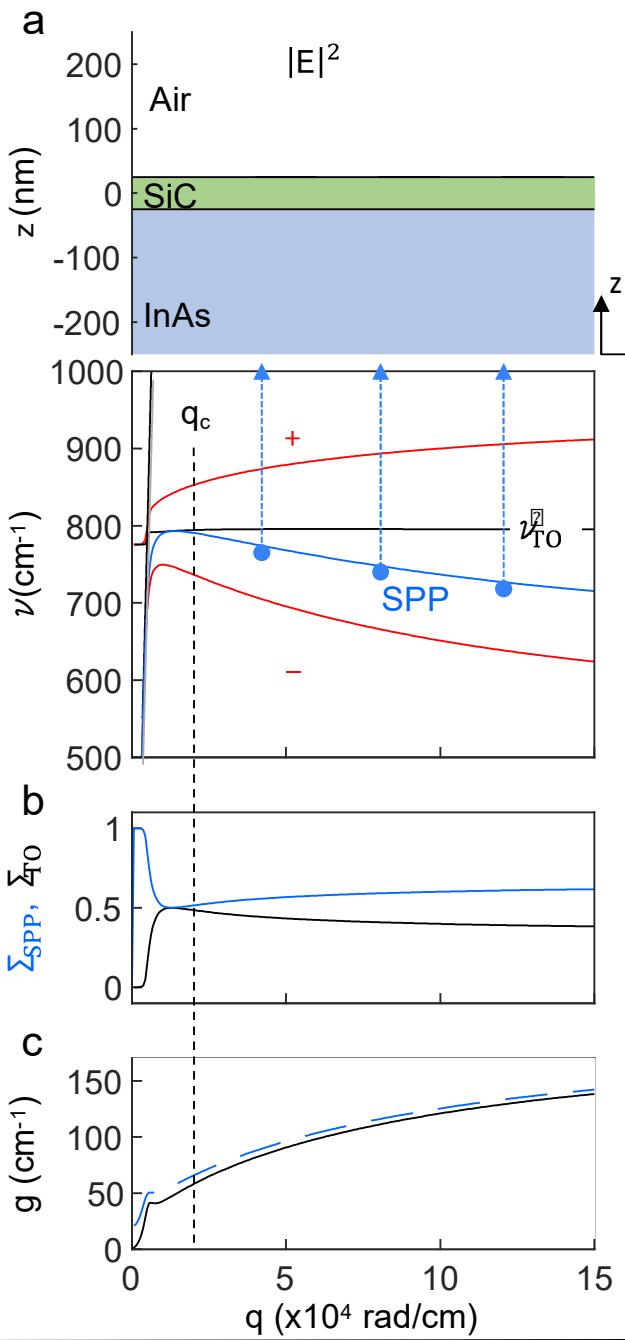
a



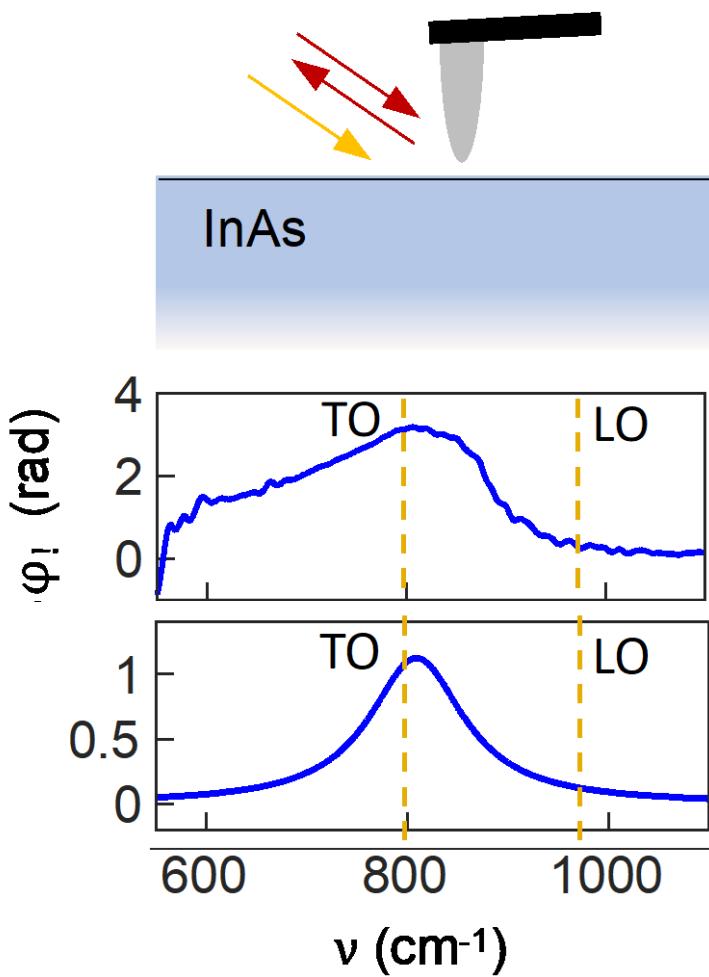
InAs
 $n=10^{17} \text{ cm}^{-3}$





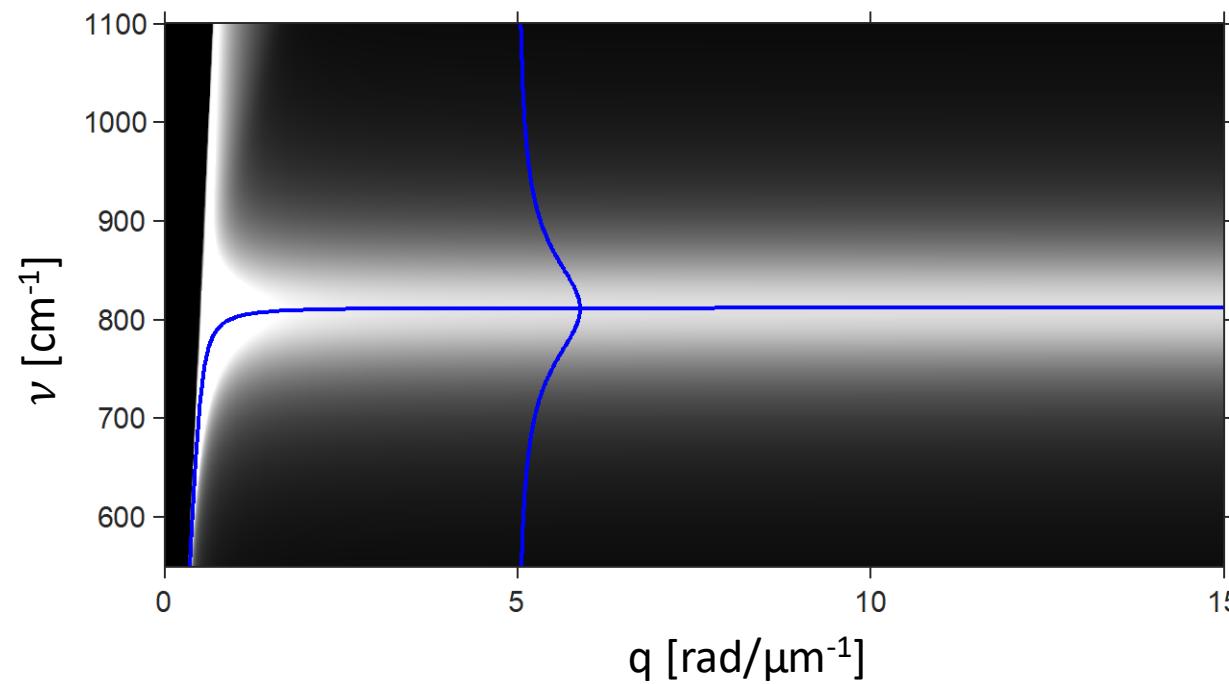


Pump-probe nanoFTIR of InAs



TM reflectivity as function of frequency [ω] and in-plane momentum [q]
Reflectivity poles -> mode dispersion

AFM tip $k \sim 1/R_{tip}$



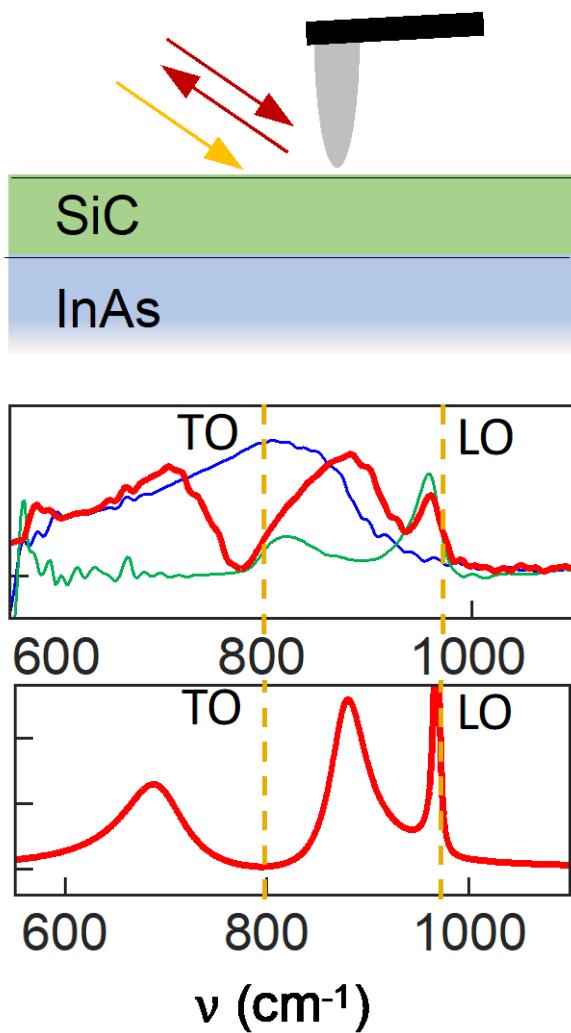
$$\Delta t = 8.5 \text{ ps}$$

$$\epsilon_{\text{InAs}}(\nu)$$

$$\nu_p = 845 \text{ cm}^{-1}$$

$$\gamma_p = 125 \text{ cm}^{-1}$$

Pump-probe nanoFTIR of InAs/SiC



TM reflectivity as function of frequency [ω] and in-plane momentum [q]
Reflectivity poles -> mode dispersion

AFM tip $k \sim 1/R_{tip}$

